

SFAF501G - SFAF508G

Isolated 5.0 AMPS.
Glass Passivated Super Fast Rectifiers

ITO-220AC

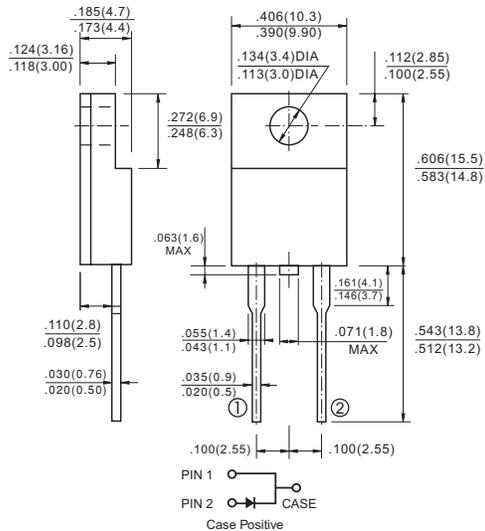


Features

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application

Mechanical Data

- ✧ Case: ITO-220AC molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free. solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C/10 seconds .16" (4.06mm) from case.
- ✧ Weight: 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SFAF 501G	SFAF 502G	SFAF 503G	SFAF 504G	SFAF 505G	SFAF 506G	SFAF 507G	SFAF 508G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_c = 100^\circ\text{C}$	$I_{(AV)}$	5.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125								A
Maximum Instantaneous Forward Voltage @ 5.0A	V_F	0.975			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$	I_R	10				400				uA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	35								nS
Typical Junction Capacitance (Note 2)	C_j	70								pF
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	5.0								$^\circ\text{C/W}$
Operating Temperature Range	T_J	-65 to +150								$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150								$^\circ\text{C}$

- Notes:
1. Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
 3. Thermal Resistance from Junction to Case Mounted on Heatsink Size of 2" x 3" x 0.25" al-Plate.

RATINGS AND CHARACTERISTIC CURVES (SFAF501G THRU SFAF508G)

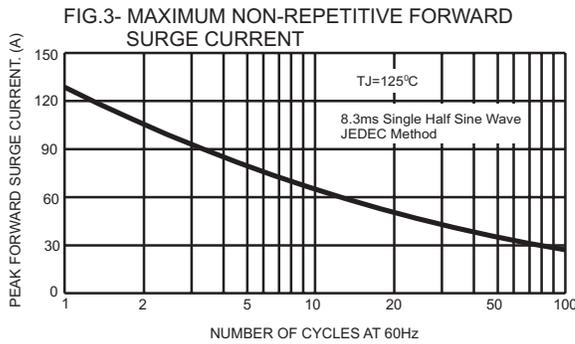
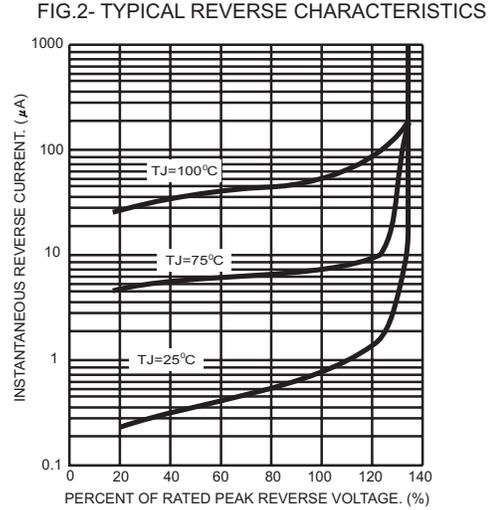
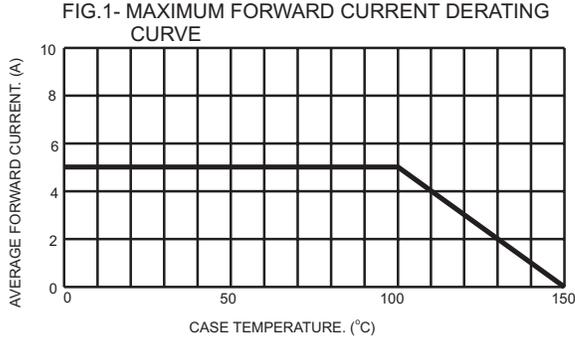


FIG.5- TYPICAL FORWARD CHARACTERISTICS

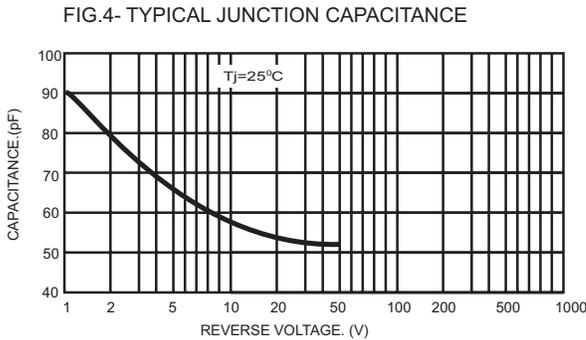
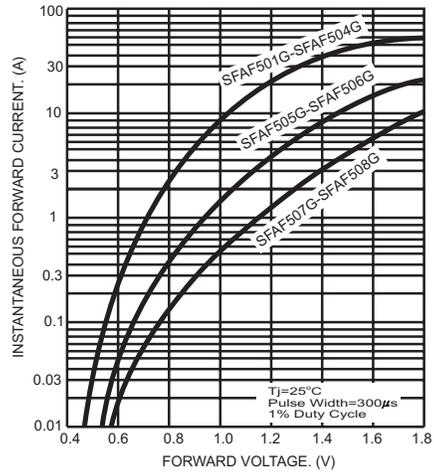


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

